



WG6: Wide bandgap and innovative sensor materials

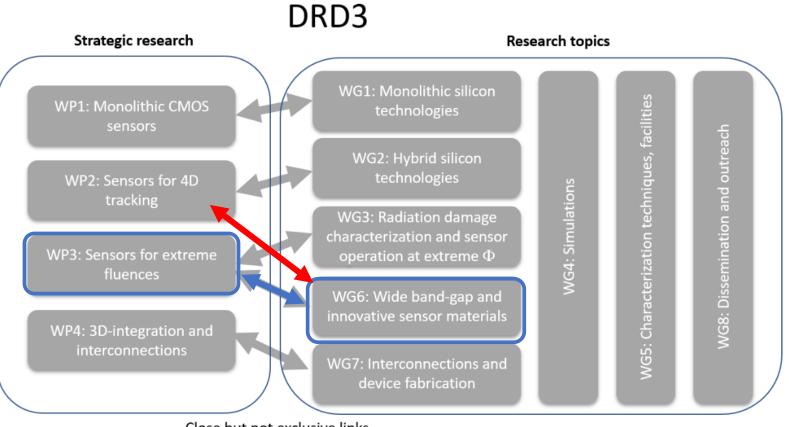
Discussion

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1st DRD3 Week on Solid State Detectors R&D, 20 June 2024



Relationship Between WPs and WGs DRD3



Close but not exclusive links between corresponding WP and WG



Work Package Tasks



Direct Connection

- 3.1 Extreme fluence: wide band-gap materials (SiC, GaN)
- 3.2 Extreme fluence: diamond-based detectors

Intrinsic Connection

- 2.1 4D tracking: 3D sensors (3D diamond, 3D SiC etc)
- 2.2 4D tracking LGAD (SiC-LGAD)



WG6: Research Goals



2024 - 2026

- RG 6.1: Development of small cell 3D diamond detectors
- RG 6.2: Fabrication of large area Diamond, SiC and GaN detectors, improve material quality and reduce defect levels
- RG 6.3: Improve tracking and timing capabilities of WBG materials
- RG 6.4: Apply graphene and/or other 2D materials in radiation detectors, understand signal formation



Towards WPs



- Synergies between existing programs
 - E.g: Many SiC activities on-going
- Common tasks
 - TCAD model, Readout Board development
- Future regular meeting every month?
 - At least 2-3 meetings between the two DRD3 meetings
 - Exchange common items progress
 - make detailed technical discussion happen
 - Coordinate DRD3 agenda
- Will be announced with e-group: <u>drd3-wg6-non-silicon@cern.ch</u>







Comments, Suggestions, Questions:

<u>drd3-wg6-conveners@cern.ch</u>